

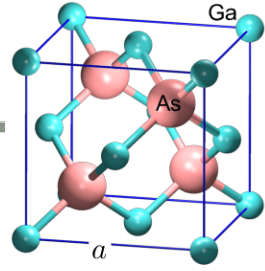


Full band Monte Carlo simulation of thermal transport in GaAs nanostructures based on ab initio calculation

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Introduction

➤ Heat Transport at the Nanoscale

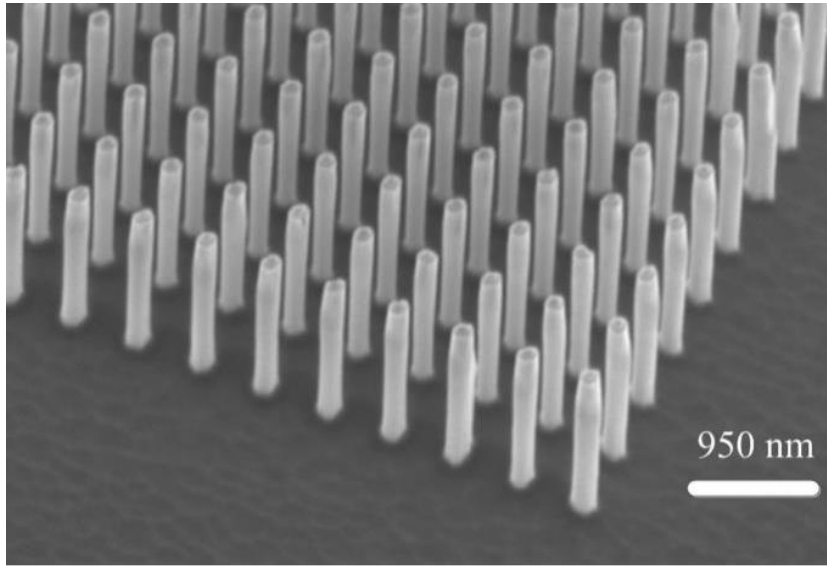


Figure 1. SEM image of vertically etched GaAs nanowire array

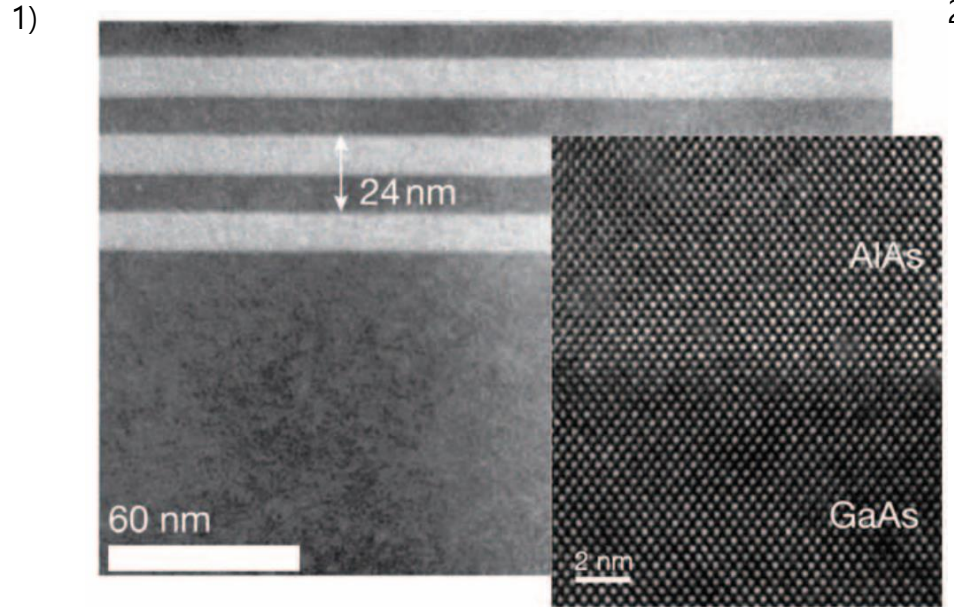


Fig. 1. (A) Cross-sectional TEM image of the 3-period (pd) SL.

✓ Semi-classical approaches by Fourier's law are no longer valid at the nanoscale
 $(q = -k\nabla T)$



< Diffusive (Fourier) >



< Intermediate >



< Ballistic >

Method

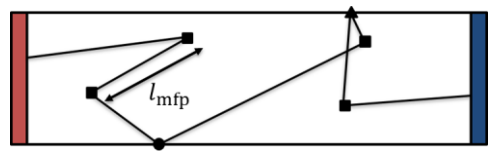
➤ Boltzmann transport equation for phonons

✓ The BTE is solved in the frame of **the relaxation time approximation** (RTA)

<BTE>	<Relaxation time approximation>
$\vec{v}_g \frac{\partial f}{\partial r} + \frac{\partial f}{\partial t} = \left(\frac{\partial f}{\partial t} \right)_{coll}$	$\left(\frac{\partial f}{\partial t} \right)_{coll} = - \frac{f(\vec{r}, \vec{k}, t) - f_{BE}(\vec{r}, \vec{k})}{\tau(\vec{k})}$

➤ Stochastic solution of BTE by Monte Carlo method ³⁾

- Phonons as pseudo-particles
- Random draw for free flights and scatterings
- Reconstruction of f from trajectories

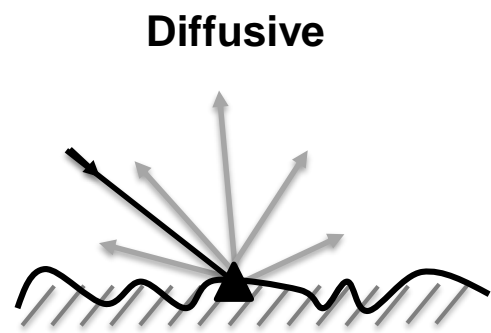
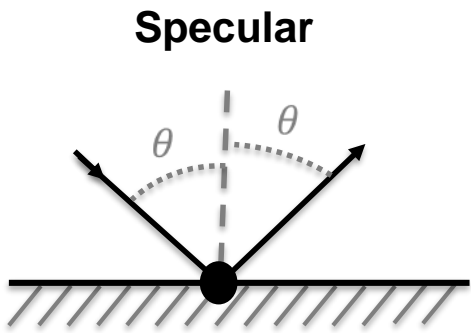


➤ This work :

“Monte Carlo simulation parametrized by **ab initio calculations**”

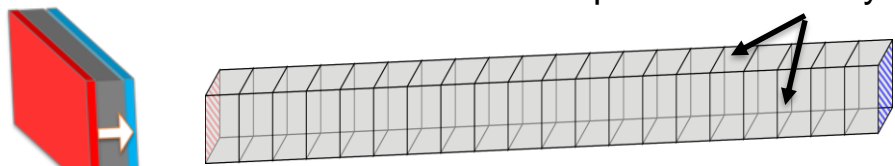
Method

➤ **Boundary condition**⁴⁾ Phonon collides with external boundaries ➡ Reflection!

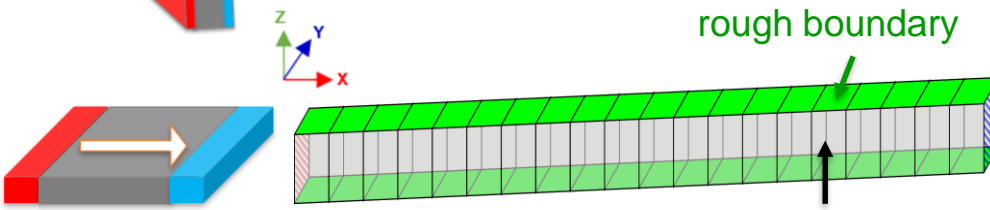


➤ **Device configuration**⁵⁾

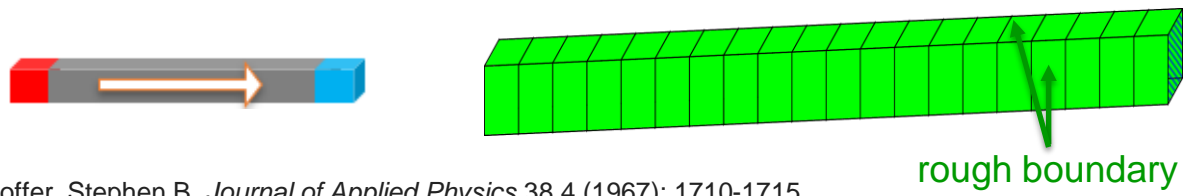
1) Nanofilm in cross-plane configuration (**CPNF**)



2) Nanofilm in in-plane configuration (**IPNF**)



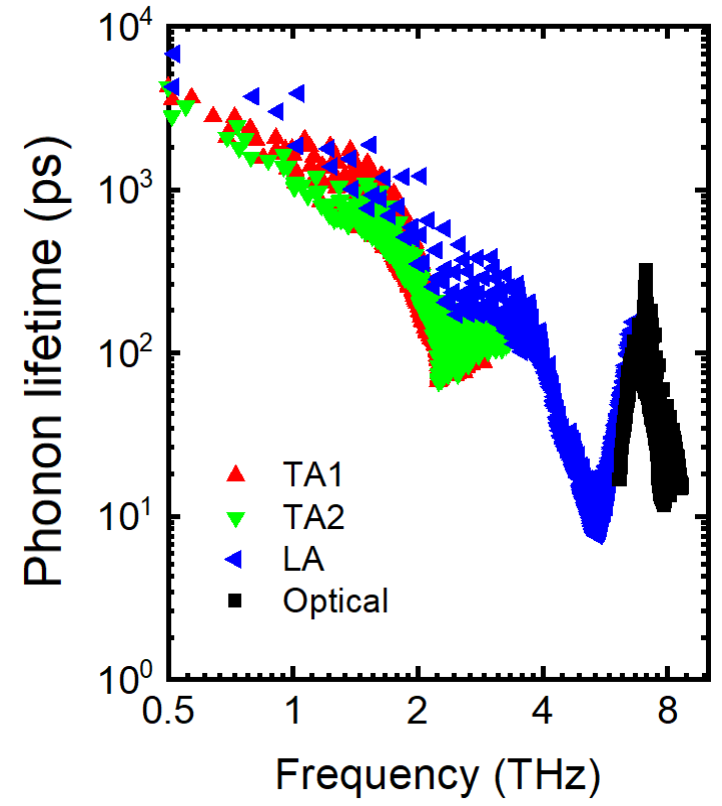
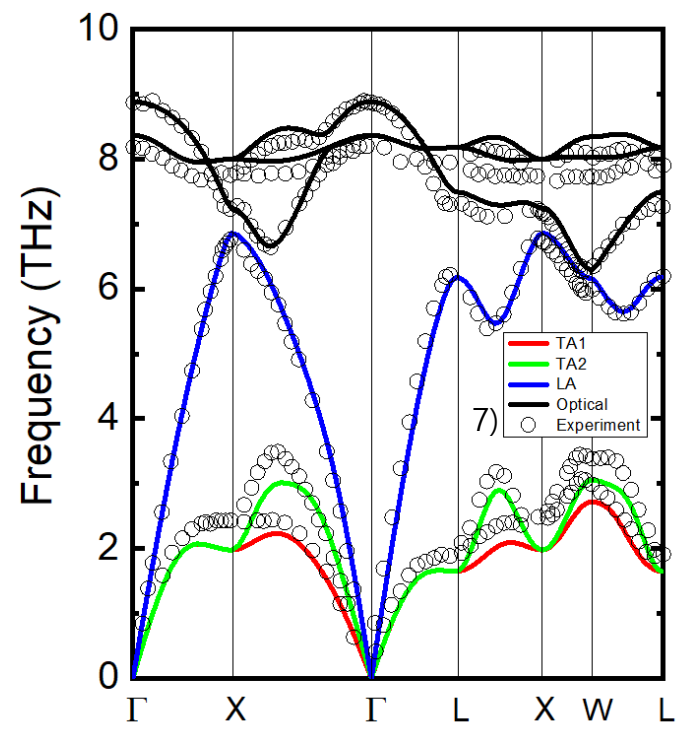
3) Rough nanowire (**NW**)



4) Soffer, Stephen B. *Journal of Applied Physics* 38.4 (1967): 1710-1715
 5) Davier, B., et al. *Journal of Physics: Condensed Matter* 30.49 (2018): 495902

Results

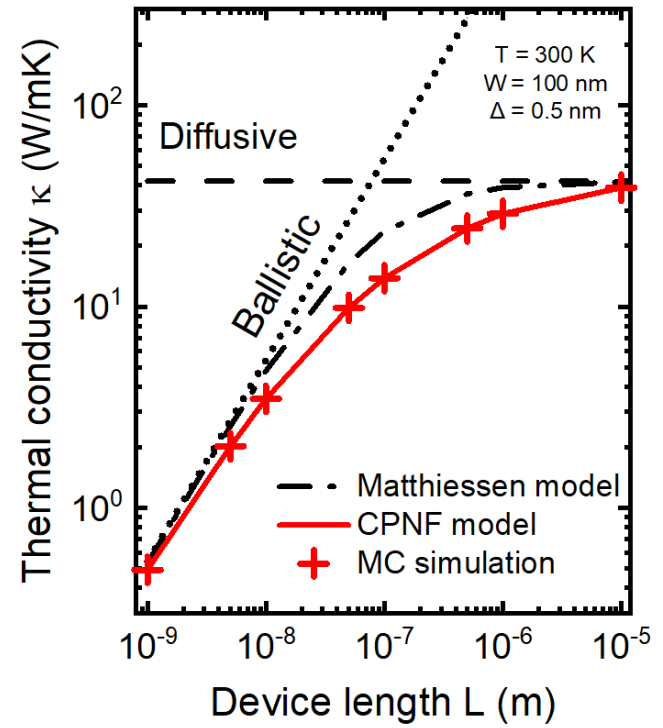
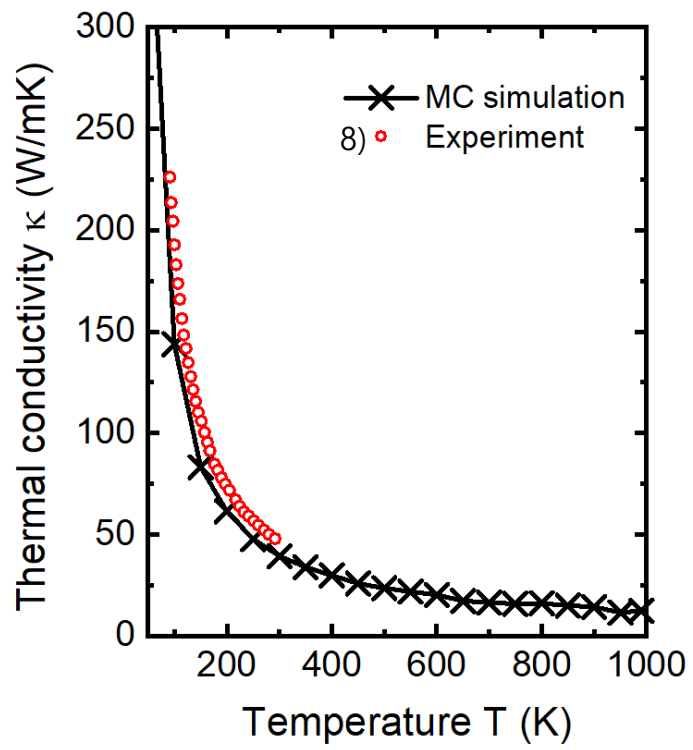
➤ Full-band description of Bulk GaAs



✓ Phonon dispersions and scattering rates was computed via ab initio methods

Results

➤ Thermal conductivity of GaAs

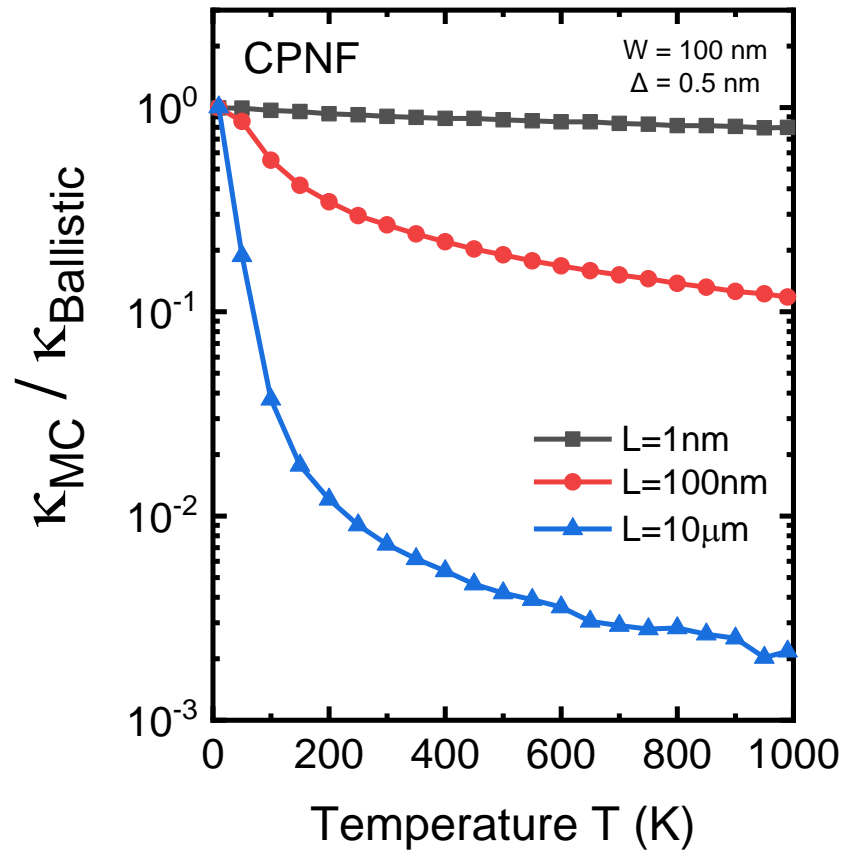


- ✓ MC results agree with the experiment data in the temperature range from 90 K to 300 K
- ✓ The Matthiessen model cannot properly capture the transition regime

Results

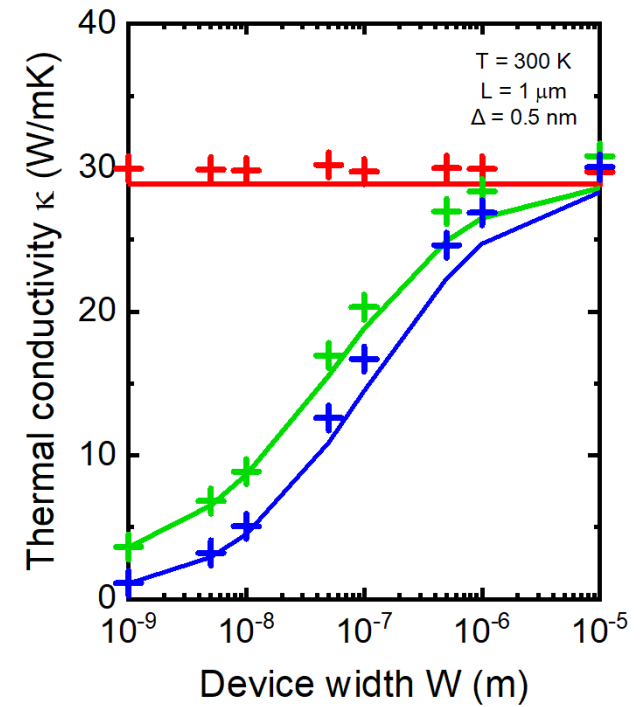
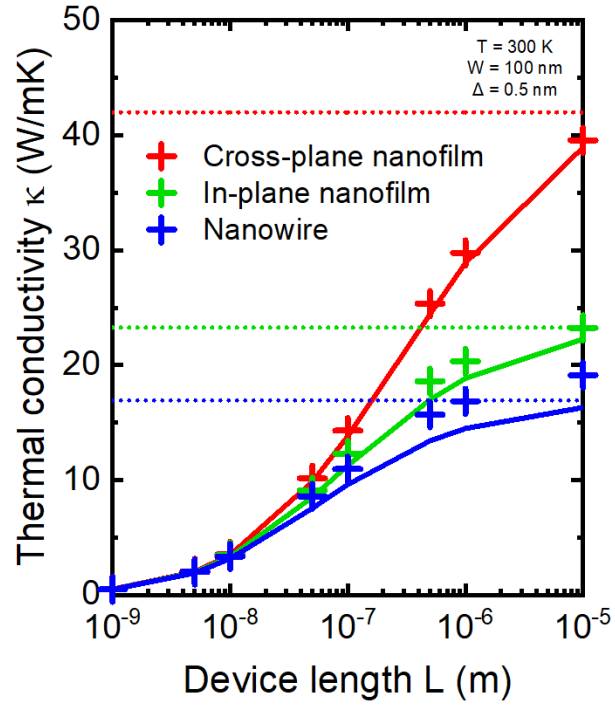
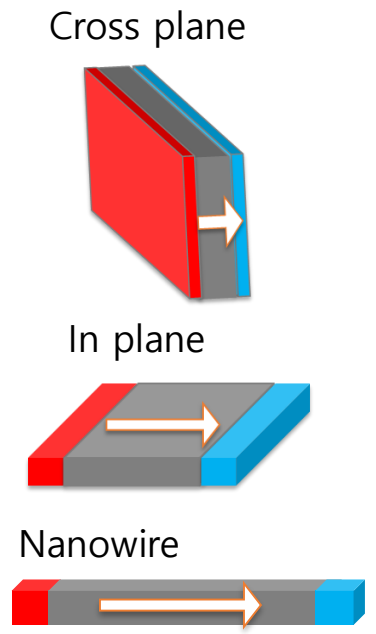
➤ The degree of ballistic transport

Knudsen number : $K_D = \frac{\kappa_{MC}}{\kappa_{Ballistic}}$



Results

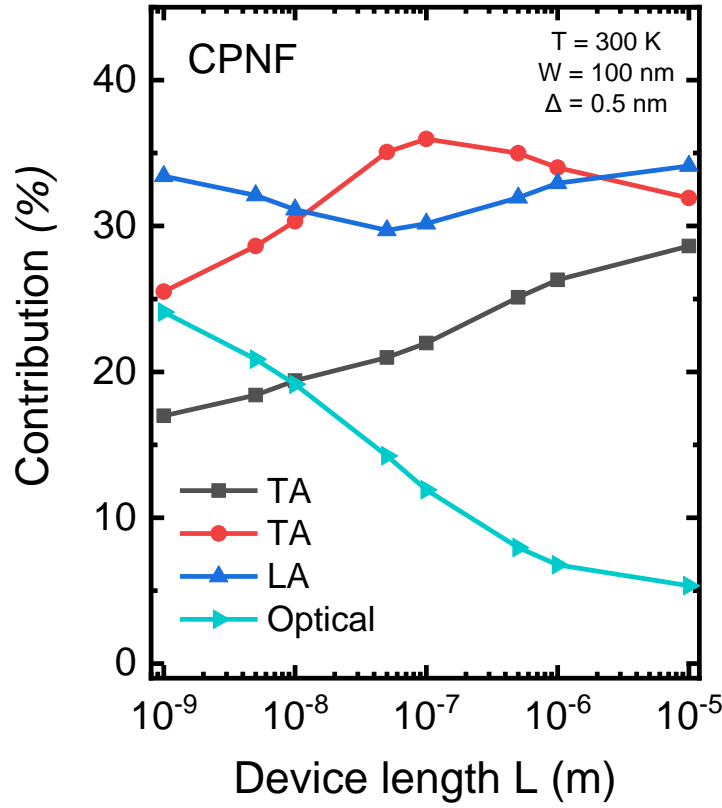
➤ Thermal conductivity a function of length L and width W



✓ The conductivity reduction is directly related to **the number of rough boundaries** when the heat transport is diffusive

Results

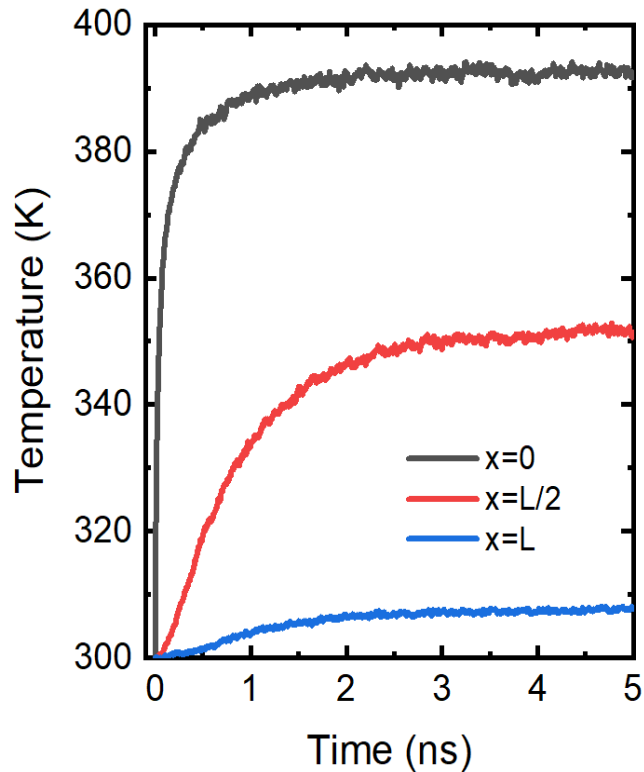
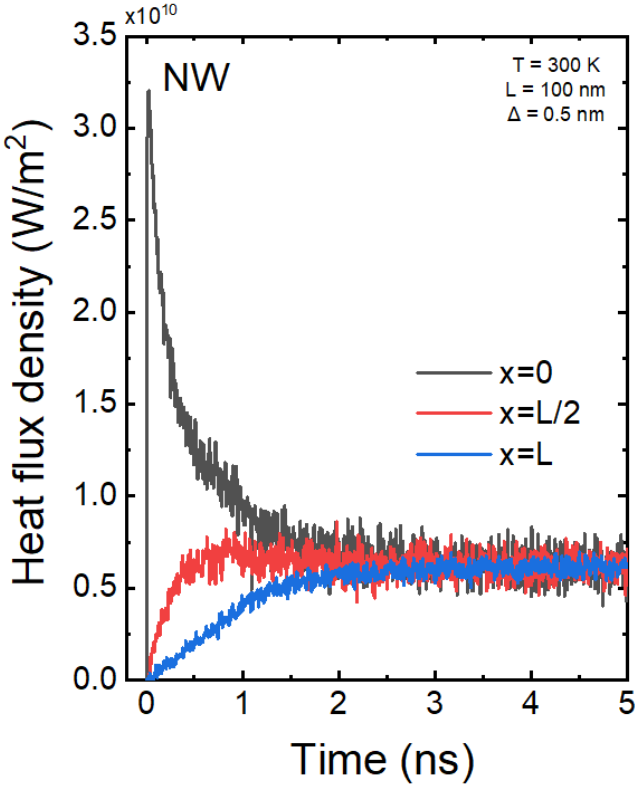
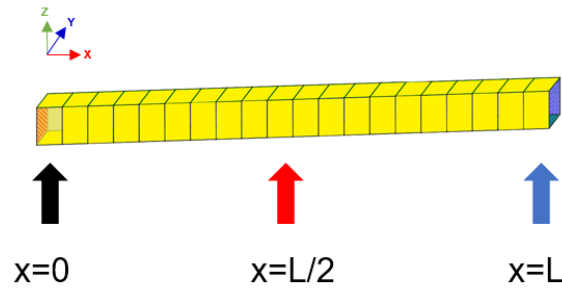
➤ Contribution of each phonon mode as a function of length L



✓ Optical phonons can contribute over **20%** to the thermal conductivity of nanostructures as compared to **5% in bulk**.

Results

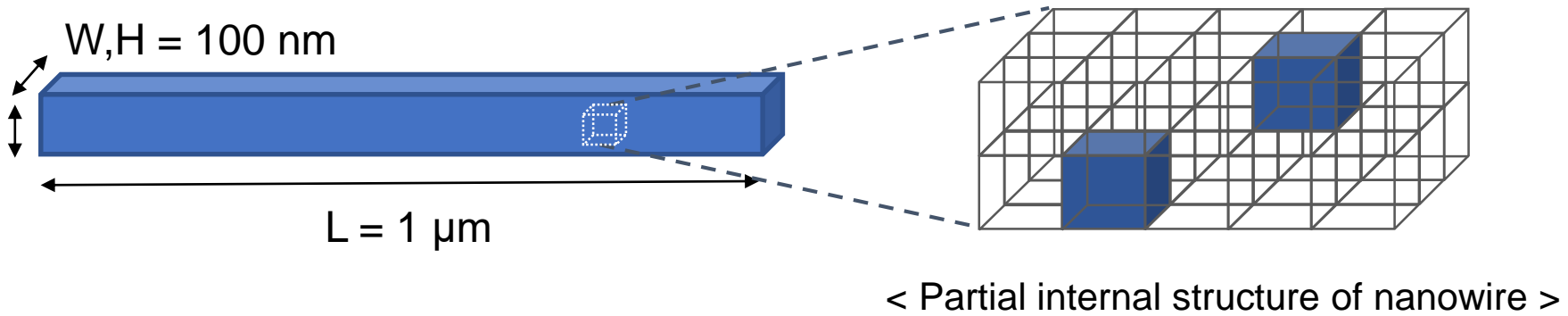
➤ Transient thermal response for NW



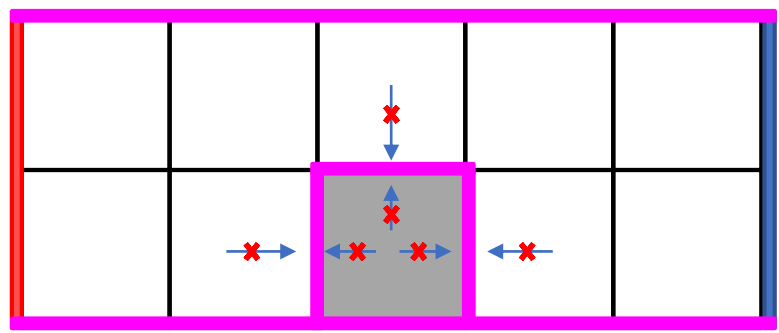
✓ The transient thermal response is investigated by analyzing the time evolution of heat flux density at different positions

Results

➤ Porous nanowire (NW)

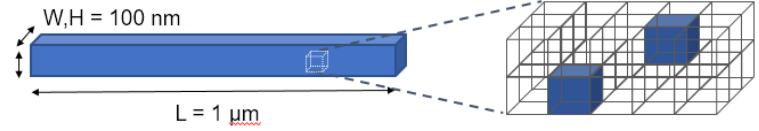


- To mimic the effect of nanopores, their boundaries are assumed to be **diffusive boundaries**

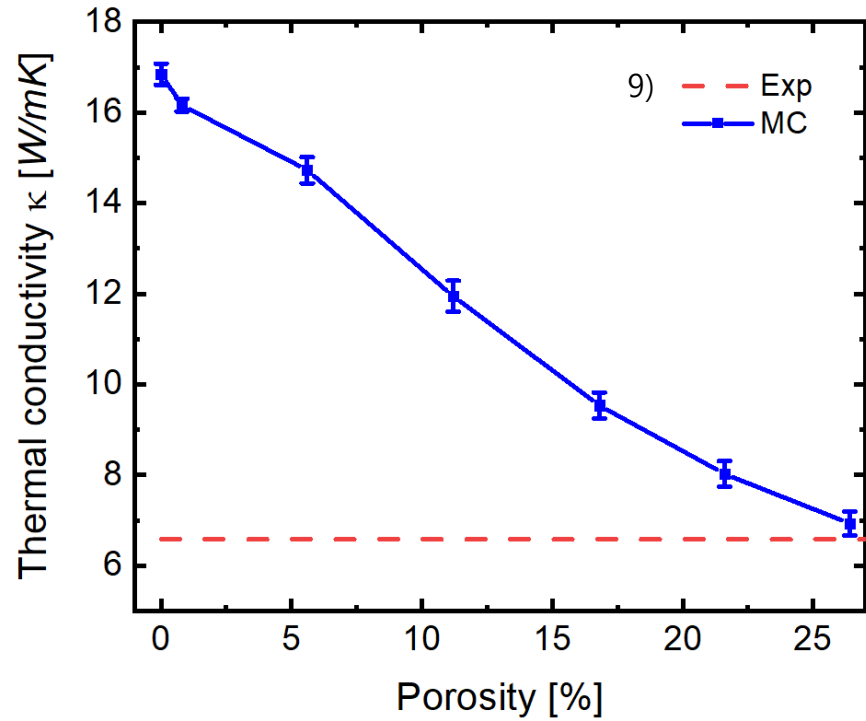


Results

➤ Thermal conductivity of porous NW



< Partial internal structure of nanowire >



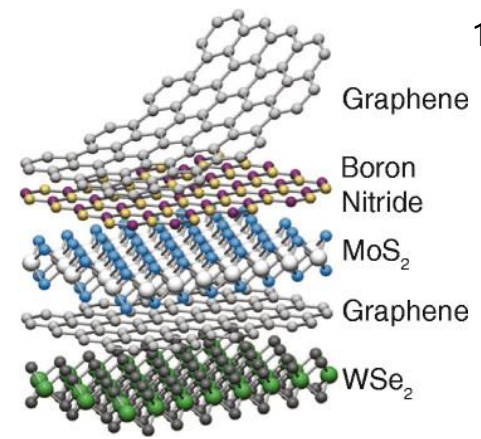
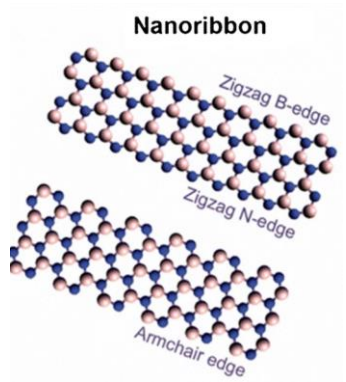
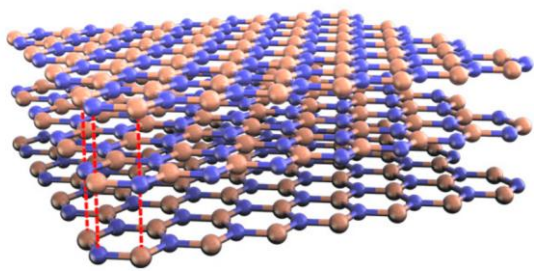
✓ **Degradation effect of nanopores** on the thermal conductivity according to the porosity of GaAs nanowires

Conclusions

➤ Conclusions

- ✓ Theoretical investigations of nanostructures using the home-made Monte Carlo simulator using full-band DFT data for material (**Full band MC-DFT**)
- ✓ We investigate **the dependence of thermal conductivity** on several parameters and observe especially the transition between ballistic and diffusive transport regimes, and their optical contribution

➤ Prospective work



➤ **Centre de Nanosciences et de Nanotechnologies (C2N)**



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Thank you for your attention